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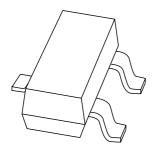
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



PBSS4240T40 V; 2 A NPN low V_{CEsat} (BISS) transistor

Product data sheet Supersedes data of 2001 Jul 13 2004 Jan 09



40 V; 2 A NPN low V_{CEsat} (BISS) transistor

PBSS4240T

FEATURES

- Low collector-emitter saturation voltage
- · High current capability
- Improved device reliability due to reduced heat generation
- Replacement for SOT89/SOT223 standard packaged transistors.

APPLICATIONS

- · Supply line switching circuits
- · Battery management applications
- DC/DC converter applications
- · Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers).

DESCRIPTION

NPN low V_{CEsat} transistor in a SOT23 plastic package. PNP complement: PBSS5240T.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
PBSS4240T	ZE*

Note

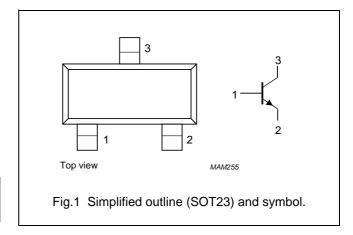
- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V_{CEO}	collector-emitter voltage	40	V
I _{CM}	peak collector current	3	Α
R _{CEsat}	equivalent on-resistance	<200	mΩ

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



ORDERING INFORMATION

TYPE	PACKAGE			
NUMBER	NAME	IE DESCRIPTION VERSION		
PBSS4240T	_	plastic surface mounted package; 3 leads	SOT23	

40 V; 2 A NPN low V_{CEsat} (BISS) transistor

PBSS4240T

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	40	V
V_{CEO}	collector-emitter voltage	open base	_	40	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
I _C	collector current (DC)		-	2	Α
I _{CM}	peak collector current		-	3	Α
I _{BM}	peak base current		_	300	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	300	mW
		T _{amb} ≤ 25 °C; note 2	-	480	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.
- 2. Device mounted on a printed-circuit board, single sided copper, tinplated and mounting pad for collector 1 cm².

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to	in free air; note 1	417	K/W
	ambient	in free air; note 2	260	K/W

Notes

- 1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.
- 2. Device mounted on a printed-circuit board, single sided copper, tinplated and mounting pad for collector 1 cm².

40 V; 2 A NPN low V_{CEsat} (BISS) transistor

PBSS4240T

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	I _E = 0; V _{CB} = 30 V	-	_	100	nA
		I _E = 0; V _{CB} = 30 V; T _j = 150 °C	-	_	50	μΑ
I _{EBO}	emitter-base cut-off current	I _C = 0; V _{EB} = 4 V	_	_	100	nA
h _{FE}	DC current gain	I _C = 100 mA; V _{CE} = 2 V	350	470	_	
		I _C = 500 mA; V _{CE} = 2 V	300	450	_	
		I _C = 1 A; V _{CE} = 2 V	300	420	_	
		I _C = 2 A; V _{CE} = 2 V	150	250	_	
V _{CEsat}	collector-emitter saturation	I _C = 100 mA; I _B = 1 mA	_	45	70	mV
	voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	_	70	100	mV
		I _C = 750 mA; I _B = 15 mA	-	120	180	mV
		I _C = 1 A; I _B = 50 mA; note 1	_	130	180	mV
		I _C = 2 A; I _B = 200 mA; note 1	_	240	320	mV
R _{CEsat}	equivalent on-resistance	$I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1	-	140	<200	mΩ
V _{BEsat}	base-emitter saturation $I_C = 2 \text{ A}$; $I_B = 200 \text{ mA}$; note 1 voltage		-	_	1.1	V
V _{BEon}	base-emitter turn on voltage	I _C = 100 mA; V _{CE} = 2 V	_	_	0.75	V
C _c	collector capacitance	I _E = I _e = 0; V _{CB} = 10 V; f = 1 MHz	_	15	20	pF
f _T	transition frequency	$I_C = 100 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	100	230	_	MHz

Note

1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

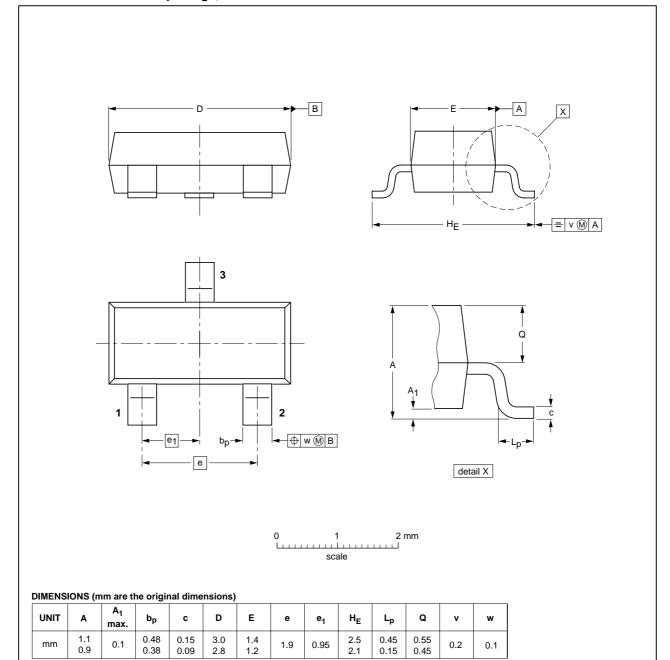
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PBSS4240T

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	TLINE REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION ISSUE DAT	
SOT23		TO-236AB				-04-11-04 06-03-16

40 V; 2 A NPN low V_{CEsat} (BISS) transistor

PBSS4240T

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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